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# Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup>



DPAK (TO-252AA)

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	15 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.2 V							
t <sub>rr</sub> (typ.)	22 ns							
T <sub>J</sub> max.	175 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Single							

### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub> and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 130 °C	15							
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	A						
Peak repetitive forward current	I <sub>FM</sub>	$T_{C} = 130 \ ^{\circ}C, f = 20 \ kHz, d = 50 \ \%$	30							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS									
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-					
Forward voltage	V	I <sub>F</sub> = 15 A	1.6	2.1	V					
	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.2	1.6					
Deverse leekeese eurrent	1	$V_{R} = V_{R}$ rated	-	-	50	μA				
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500					
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH				

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RoHS

COMPLIANT

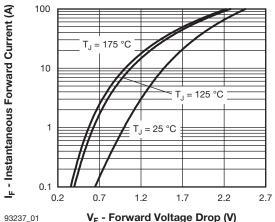
HALOGEN

FREE



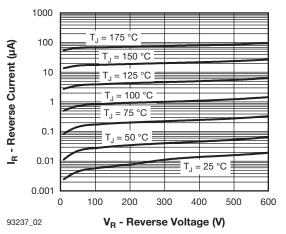
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	22	30				
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	36	-	ns			
		T <sub>J</sub> = 125 °C		-	75	-				
Pools receivers ourrent		T <sub>J</sub> = 25 °C	l <sub>F</sub> = 15 A dl <sub>F</sub> /dt = 200 A/µs	-	4.8	-	A			
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	7.2	-				
	0	T <sub>J</sub> = 25 °C		-	90	-	20			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	300	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.4	1.8	°C/W				
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	70	0/10				
Approvimeto weight				0.3						
Approximate weight				0.01		oz.				
Marking device		Case style DPAK (TO-252AA)	15EWH06FN							

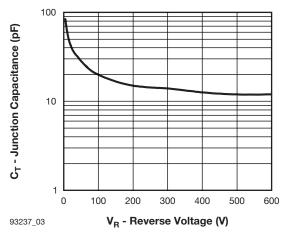


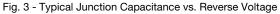
V<sub>F</sub> - Forward Voltage Drop (V)

Fig. 1 - Typical Forward Voltage Drop Characteristics

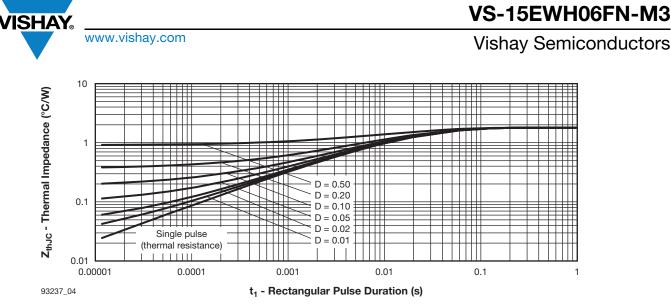








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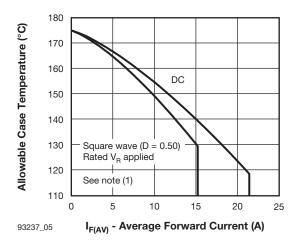


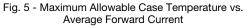


100

90

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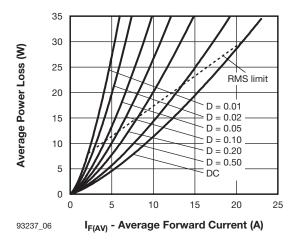


Fig. 6 - Forward Power Loss Characteristics

### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6);$  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

80 I<sub>F</sub> = 15 A, T<sub>.1</sub> = 125 °C 70 60 t<sub>rr</sub> (ns) 50 40 30 I<sub>F</sub> = 15 A, T<sub>J</sub> = 25 °C 20 10 0 100 1000 dl<sub>F</sub>/dt (A/µs)



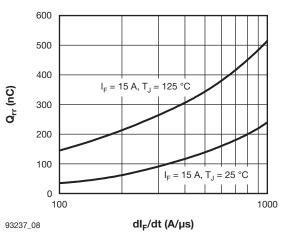


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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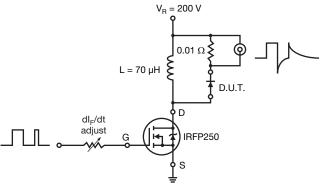
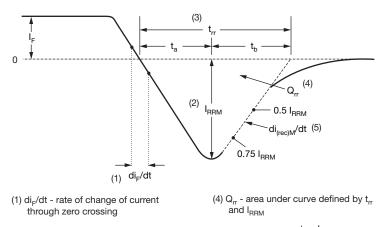
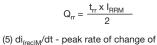


Fig. 9 - Reverse Recovery Parameter Test Circuit



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(2) I<sub>RRM</sub> - peak reverse recovery current
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(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.



current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 10 - Reverse Recovery Waveform and Definitions

**ORDERING INFORMATION TABLE** 

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ISHA

Device code	VS-	15	E	w	н	06	FN	TRL	-M3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
	1	- Vis	hay Sen	niconduo	ctors pro	oduct			
	2	- Cu	rent rati	ng (15 =	= 15 A)				
	3	- Cire	cuit conf	iguratior	า:				
		E =	single o	diode					
	4	- Pao	ckage id	entifier:					
		W :	= D-PAk	ζ.					
	5	- H=	hyperfa	st recov	very				
	6	- Vol	tage rati	ng (06 =	= 600 V)				
	7	- FN	= TO-25	52AA					
	8	- • N	one = tu	ıbe					
		• T	R = tape	e and ree	el				
		• T	RL = tap	be and re	eel (left	orienteo	d)		
		• T	RR = ta	be and r	eel (righ	nt orient	ed)		
	9	- Env	/ironmer	ntal digit	:				
		-M3	3 = halog	gen-free	, RoHS-	complia	ant, and	termina	ations le

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-15EWH06FN-M3	75	3000	Antistatic plastic tube							
VS-15EWH06FNTR-M3	2000	2000	13" diameter reel							
VS-15EWH06FNTRL-M3	3000	3000	13" diameter reel							
VS-15EWH06FNTRR-M3	3000	3000	13" diameter reel							

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?96040						

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D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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